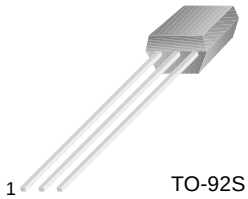
FAIRCHILD
SEMICONDUCTOR®

KSC2669

FM RADIO RF AMP, MIX, CONV, OSC, IF AMP

- High Current Gain Bandwidth Product : f_T=250MHz (TYP.)



TO-92S

1.Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	35	V
V_{CEO}	Collector-Emitter Voltage	30	V
V_{EBO}	Emitter-Base Voltage	4	V
I_C	Collector Current	30	mA
P_C	Collector Power Dissipation	200	mW
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C=100μA, I_E=0	35			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C=5mA, I_B=0	30			V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E=10μA, I_C=0	4			V
I_{CBO}	Collector Cut-off Current	V_{CB}=30V, I_E=0			0.1	μA
I_{EBO}	Emitter Cut-off Current	V_{EB}=4V, I_C=0			0.1	μA
h_{FE}	DC Current Gain	V_{CE}=12V, I_C=2mA	40		240	
V_{BE} (on)	Base-Emitter On Voltage	V_{CE}=6V, I_C=1mA	0.65	0.70	0.75	V
V_{CE} (sat)	Collector-Emitter Saturation Voltage	I_C=10mA, I_B=1mA		0.1	0.4	V
f_T	Current Gain Bandwidth Product	V_{CE}=10V, I_C=1mA	100	250		MHz
C_{ob}	Output Capacitance	V_{CB}=10V, I_E=0, f=1MHz		2.0	3.2	pF

h_{FE} Classification

Classification	R	O	Y
h_{FE}	40 ~ 80	70 ~ 140	120 ~ 240

Typical Characteristics

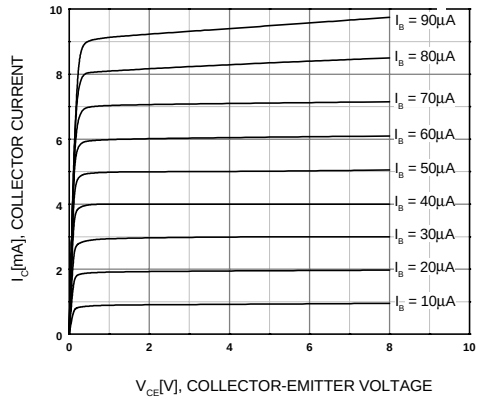


Figure 1. Static Characteristic

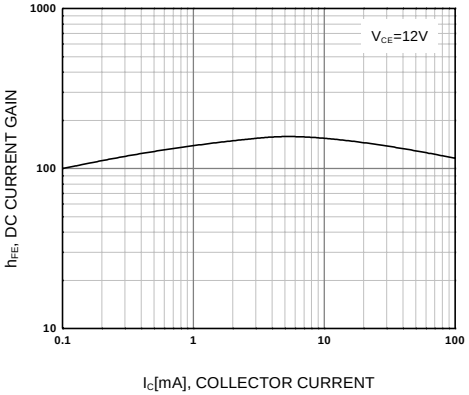


Figure 2. DC current Gain

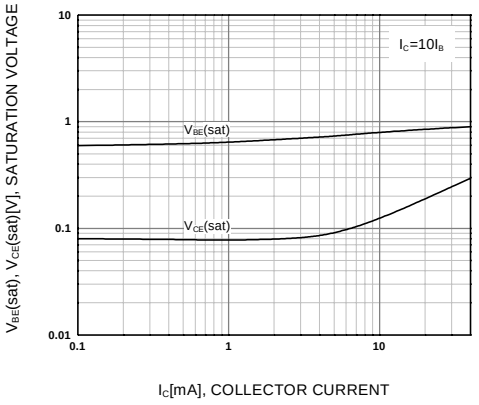


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

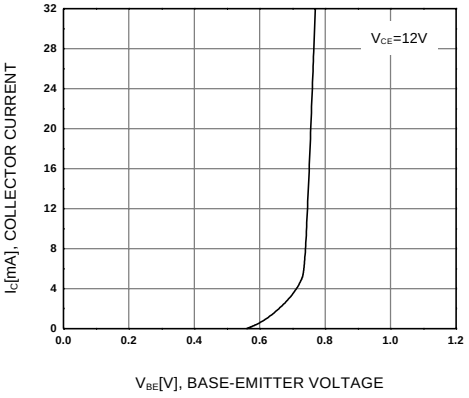


Figure 4. Base-Emitter On Voltage

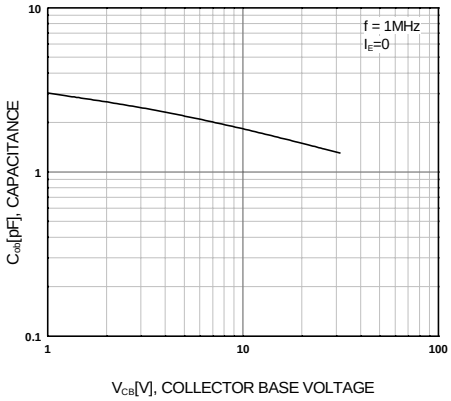


Figure 5. Collector Output Capacitance

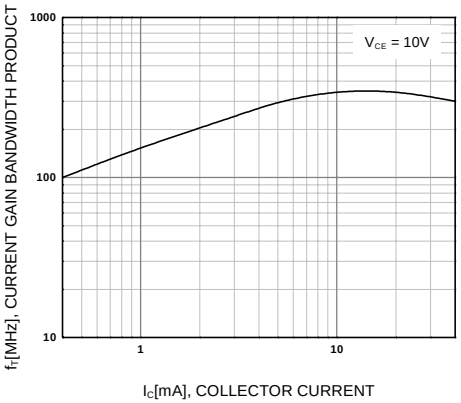
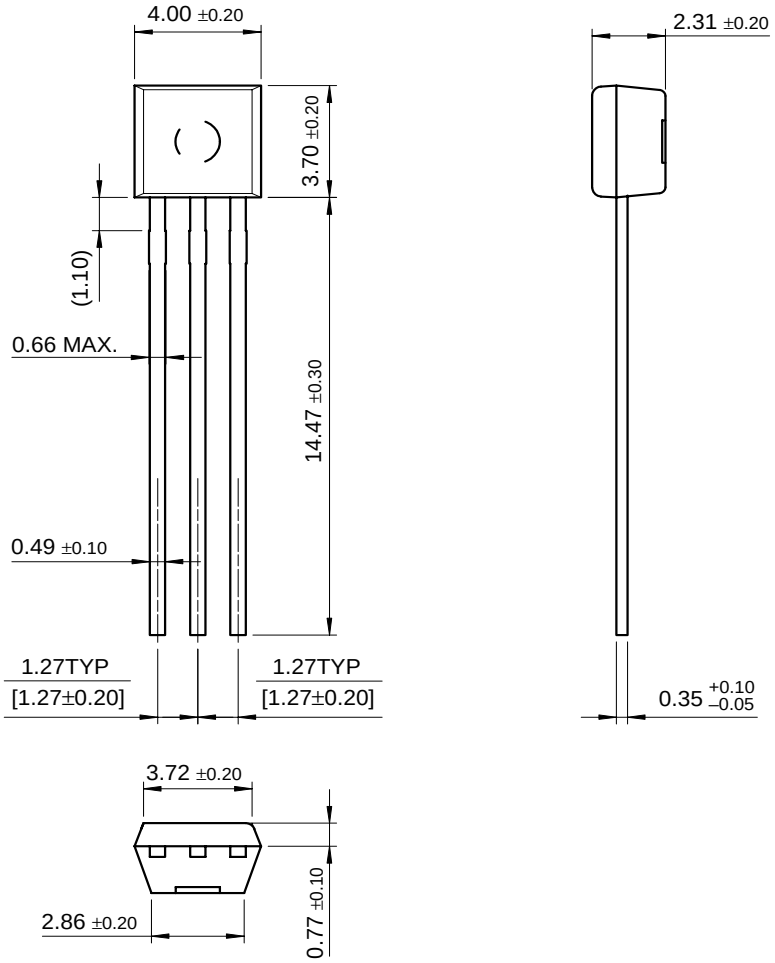


Figure 6. Current Gain Bandwidth Product

Package Dimensions

TO-92S



Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E^2CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C™	OCX™	RapidConfigure™	UHC™
Across the board. Around the world.™		OCXPro™	RapidConnect™	UltraFET®
The Power Franchise™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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